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Serial No.: 10/605,135

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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re patent application of

Docket No.: FIS920030184US1

Dureseti Chidambarrao, et al.

Serial No.: 10/605,135

Group Art Unit: No. 2829

Filed: September 10, 2003

Examiner: Kilday, Lisa A.

For: **METHOD AND STRUCTURE FOR IMPROVED MOSFETs USING
POLY/SILICIDE GATE HEIGHT CONTROL**

Mail Stop: Non-final amendment
Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

RESPONSE TO RESTRICTION REQUIREMENT AND AMENDMENT

Sir:

In response to the Restriction Requirement dated June 16, 2004, Applicants elect claims 1-13 and 20, without traverse, and amend claim 11 as follows.

Applicants believe that no extensions of time or fees for net addition of claims are required at this time. However, if additional extensions of time are necessary to prevent abandonment of this application, then such extensions of time are hereby petitioned under 37 C.F.R. §1.136(a), and any fees required therefor (including fees for net addition of claims) are hereby authorized to be charged to International Business Machines Corporation's deposit Account No. 09-0458.